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CERTIFICATE OF MAILING

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Dated Dounter 14, 2005 By Delie & King

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Abdalla Aly Naem, et al.

Appln. No.: 10/772,863

Filed: February 4, 2004

For: METHOD OF FORMING A MOS TRANSISTOR WITH A LAYER OF SILICON GERMANIUM CARBON (as

amended)

Group Art Unit: 2823

Examiner: William M. Brewster

AMENDMENT IN RESPONSE TO OFFICE ACTION MAILED AUGUST 23, 2005

INTRODUCTORY COMMENTS

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Dear Sir:

In response to the Official Action mailed August 23, 2005, please amend the above-identified application as indicated in the following:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper;

Remarks which begin on page 4 of this paper; and

Appendix A which begins on page 8 of this paper.